# Multi-layer ceramic chip capacitors

# MCH03 (0603 size, chip capacitor)

#### Features

- 1) Small size (0.6 x 0.3 x 0.3 mm) makes it perfect for lightweight portable devices.
- Comes packed either in tape to enable automatic mounting.
- 3) Precise uniformity of shape and dimensions facilitates highly efficient automatic mounting.
- 4) Barrier layer and end terminations to improve solderability.



#### • External dimensions (Units : mm)









# MCH03

# Ceramic capacitors

#### Capacitance range

#### For thermal compensation

Part n	MCH03	
Capacitance (pF)	Temperature characteristics	A (CG) (C0G)
Capacitance (pr)	Rated voltage (V) Tolerance	25V
0.5 0.75 1		
1.1 1.2 1.3		
1.5 1.6 1.8	C (±0.25pF)	
2 2.2 2.4		
2.7 3 3.3		
3.6 3.9 4		
4.3 4.7 5		
5.1 5.6 6		
6.2 6.8 7	D ( ± 0.5pF)	
7.5 8 8.2		
9 9.1 10		

Part number		MCH03
Capacitance (pF)	Temperature characteristics	A (CG) (C0G)
Capacitance (pr)	Rated voltage (V) Tolerance	25V
11		
12		
13	ļ	
15		
16		
18	ļ .	
20		
22	J (±5%)	
24		
27		
30		
33		
36		
39		
43		
47		

Product thickness (mm) 0.3±0.03

#### High dielectric constant

Part number		MCH03	
Capacitance (pF)	Temperature characteristics	CN (R) (B) (X7R)	FN (F) (Y5V)
	Rated voltage (V)	25V	25V
	Tolerance	K ( ±10%)	Z ( +80, -20%)
100 150 200			
330 470 680			
1,000 1,500 2,200			
4,700 10,000			

Product thickness (mm) 0.3±0.03



# Ceramic capacitors

#### Characteristics

#### Class 1 (For thermal compensation)

	Temperature characteristics	A (CG) (C0G)	Test methods/conditions	
Item		· / · · · · /	(based on JIS C 5102)	
Operating temperature		–55°C ∼ 125°C		
Nominal capacitance (C)		Must be within the specified tolerance range.	Based on paragraph 7.8 and paragraph 9 Measured at room temperature and standard humidity,	
Dissipation factor (tanδ)		100/(400+20C)% or less: Less than 30 pF 0.1% or less : 30 pF or larger		
Insulation resis	tance (IR)	10,000 M\Omega or 500 M\Omega $\cdot\mu\text{F},$ whichever is smaller	Based on paragraph 7.6 Measurement is made after rated voltage is applied for 60 $\pm$ 5s.	
Withstanding v	oltage	The insulation must not be damaged.	Based on paragraph 7.1 Apply 300% of the rated voltage for 1 to 5s then measure.	
Temperature c	haracteristics	Within 0 $\pm$ 30ppm/°C	The temperature coefficients in table 12, paragraph 7.12 are calculated at 20°C and high temperature.	
Terminal adherence		No detachment or signs of detachment.	Based on paragraph 8.11. 2. Apply 2N for $10 \pm 1s$ in the direction indicated by the arrow.	
	Appearance	There must be no mechanical damage.	Chip is mounted to a board in the manner	
Resistance to vibration	Rate of capacitance change	Must be within initial tolerance.	shown on the right, subjected to vibration	
	Dissipation factor (tanb)	Must satisfy initial specified value.	$24 \pm 2$ hrs. later. Board	
Solderability		At least 3/4 of the surface of the two terminals must be covered with new solder.	Based on paragraph 8.13 Soldering temperature: 235 ± 5°C Soldering time : 2 ± 0.5s	
	Appearance	There must be no mechanical damage.		
	Rate of capacitance change	$\pm$ 2.5% or $\pm$ 0.25 pF, whichever is larger.	Based on paragraph 8.14.	
Resistance to soldering	Dissipation factor (tano)	Must satisfy initial specified value.	Soldering temperature: 260 ± 5°C	
heat	Insulation resistance	10,000 M\Omega or 500 M\Omega $\cdot\mu\text{F},$ whichever is smaller	$\begin{tabular}{lllllllllllllllllllllllllllllllllll$	
	Withstanding voltage	The insulation must not be damaged.		
	Appearance	There must be no mechanical damage.		
	Rate of capacitance change	$\pm$ 2.5% or $\pm$ 0.25 pF, whichever is larger.	Based on paragraph 9.3	
Temperature cycling	Dissipation factor (tan \delta)	Must satisfy initial specified value.	Number of cycles : 5	
	Insulation resistance	10,000 M\Omega or 500 M\Omega $\cdot\mu\text{F},$ whichever is smaller	<ul> <li>Capacitance measured after 24 ± 2 hrs.</li> </ul>	
Humidity load test	Appearance	There must be no mechanical damage.	Based on paragraph 9.9	
	Rate of capacitance change	$\pm$ 7.5% or $\pm$ 0.75 pF, whichever is larger.	Test temperature: $40 \pm 2 \degree C$ Relative humidity: 90% to 95% Applied voltage : rated voltage Test time : 500 to 524 hrs. Capacitance measured after 24 $\pm$ 2 hrs.	
	Dissipation factor (tan \delta)	0.5% or less		
	Insulation resistance	500M  or 25M $\!\Omega\cdot\mu F,$ whichever is smaller		
High- temperature load test	Appearance	There must be no mechanical damage.	Based on paragraph 9.10 Test temperature : Max. operating temp. Applied voltage : rated voltage × 200% Test time : 1,000 to 1,048 hrs.	
	Rate of capacitance change	$\pm$ 3.0% or $\pm$ 0.3 pF, whichever is larger.		
	Dissipation factor (tan \delta)	0.3% or less		
	Insulation resistance	1,000M $\Omega$ or 50M $\Omega\cdot\mu\text{F},$ whichever is smaller	Capacitance measured after $24 \pm 2$ hrs.	



# Ceramic capacitors

Class 2 (High dielectric constant)
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<u> </u>	Femperature characteristics				
Item	remperature characteristics	CN (R) (B) (X7R)	FN (F) (Y5V)	Test methods/conditions (based on JIS C 5102)	
Operating temperature		−55°C ~ +125°C	−30°C ~ +85°C		
Nominal capacitance (C)		Must be within the specified tolerance range.		Based on paragraph 7.8 Measured at room temperature and standard humidity,	
Dissipation factor (tan $\delta$ )		2.5% or less (when rated voltage is 16V: 3.5% or less)	5.0% or less (when rated voltage is 16V: 7.5% or less)	Measurement frequency: 1 $\pm$ 0.1 kHz Measurement voltage : 1.0 $\pm$ 0.2 Vrms.	
Insulation resis	tance (IR)	10,000MΩ or 500MΩ · μ	μF, whichever is smaller	Based on paragraph 7.6 Measurement is made after rated voltage is applied for 60 $\pm$ 5s.	
Withstanding v	oltage	The insulation mus	st not be damaged.	Based on paragraph 7.1 Apply 250% of the rated voltage for 1 to 5s then measure.	
Temperature cl	haracteristics	Within ± 15%	+ 22, + 82%	The temperature coefficients in paragraph 7.12, table 8, condition B, are based on measurements carried out at $20^{\circ}$ C, with no voltage applied.	
Terminal adherence		, No detachment or signs of detachment		Based on paragraph 8. 11. 2. Apply 2N for 10 ± 1s in the direction indicated by the arrow.	
	Appearance	There must be no m	nechanical damage.	Chip is mounted to a board in the	
Resistance to vibration	Rate of capacitance change	e Must be within initial tolerance.		manner shown on the right, subjected to vibration (type A in paragraph 8.2),	
	Dissipation factor (tan $\delta$ )	Must satisfy initial specified value.		and measured 48 ± 4 hrs. later. Board	
Solderability		At least 3/4 of the surface of the two terr	ninals must be covered with new solder.	Based on paragraph 8. 13 Soldering temperature : 235 ± 5°C Soldering time : 2 ± 0.5s	
	Appearance	There must be no m	nechanical damage.		
	Rate of capacitance change	Within ± 5.0%	Within ± 20.0%	Based on paragraph 8. 14.	
Resistance to soldering	Dissipation factor (tan \delta)	Must satisfy initia	I specified value.	Soldering temperature : $260 \pm 5^{\circ}C$	
heat	Insulation resistance	10,000M\Omega or 500MΩ $\cdot\mu F,$ whichever is smaller		Soldering time: $5 \pm 0.5s$ Preheating: $150 \pm 10^{\circ}C$ for 1 to 2 min.	
	Withstanding voltage	The insulation must not be damaged.			
	Appearance	There must be no m	nechanical damage.		
Temperature	Rate of capacitance change	Within $\pm$ 7.5%	Within ± 20.0%	Based on paragraph 9.3 Number of cycles : 5	
cycling	Dissipation factor (tan $\delta$ )	Must satisfy initial specified value. 10,000MΩ or 500MΩ · μF, whichever is smaller		Capacitance measured after 48 $\pm$ 4 hrs.	
	Insulation resistance				
Rat Humidity load test	Appearance	There must be no m	There must be no mechanical damage. Based on paragraph 9.9		
	Rate of capacitance change	± 12.5% or less	Within ± 30.0%	Test temperature : 40 ± 2°C Relative humidity : 90% to 95% Applied voltage Test time : 500 to 524 hrs.	
	Dissipation factor $(tan \delta)$	5.0% or less	7.5% or less (when rated voltage is 16V: 10.0%)		
	Insulation resistance	500M\Omega or 25M $\Omega \cdot \mu F$ , whichever is smaller		Capacitance measured after 48 $\pm$ 4 hrs	
High- temperature load test	Appearance	There must be no mechanical damage.			
	Rate of capacitance change	Within ± 10.0%	Within ± 30.0%	Based on paragraph 9.10 Test temperature: Max. operating tem Applied voltage : rated voltage × 200 Test time : 1,000 to 1,048 hrs.	
	Dissipation factor $(tan \delta)$	5.0% or less	7.5% or less (when rated voltage is 16V: 10.0%)		
	Insulation resistance	1,000MΩ or 50MΩ · μl	F, whichever is smaller	Capacitance measured after 48 ± 4 h	



## Ceramic capacitors

#### • Packaging specifications





# MCH03

### Ceramic capacitors

#### Electrical characteristics







CN (X7R) Characteristics





#### FN (Y5V) Characteristics



Fig.5 Capacitance-temperature characteristics

